

Schottky Barrier Rectifier

FEATURES

- Low forward voltage drop
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

MECHANICAL DATA

Case: DO-201AD

Molding compound, UL flammability classification rating 94V-0 Base P/N with suffix "G" on packing code - halogen-free **Terminal:** Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 1A whisker test, **Polarity:** Indicated by cathode band **Weight:** 1.10g (approximately)



DO-201AD

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)					
PARAMETER	SYMBOL	1N5820	1N5821	1N5822	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	V
Maximum RMS voltage	V _{RMS}	14	21	28	V
Maximum DC blocking voltage	V _{DC}	20	30	40	V
Maximum average forward rectified current	I _{F(AV)}	3		А	
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	70			A
Maximum instantaneous forward voltage (Note 1) @ 3 A	V _F	0.475	0.500	0.525	V
Maximum reverse current @ rated VR T_J =25 $^{\circ}C$ T_J =100 $^{\circ}C$	I _R	0.5 10		mA	
Typical Junction Capacitance (Note 2)	Cj	200		pF	
Typical thermal resistance	R _{eJA}	40		^o C/W	
Operating junction temperature range	TJ	- 55 to +125 °C		°C	
Storage temperature range	T _{STG}	- 55 to +125 ^o C		°C	

Note 1: Pulse test with PW=300 µs, 1% duty cycle

Note 2: Measure at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.



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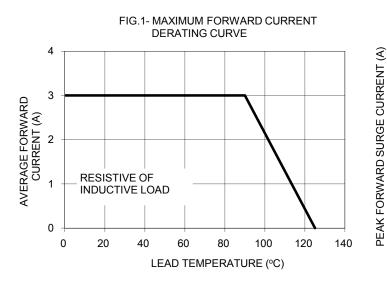
ORDERING INFORMATION						
PART NO.	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING		
		CODE				
1N582x (Note 1)	A0	- Suffix "G" -	DO-201AD	500 / AMMO box		
	R0		DO-201AD	1,250 / 13" Reel		
	B0		DO-201AD	500 / Bulk packing		
	X0		DO-201AD	Forming		

Note 1: "x" defines voltage from 20V (1N5820) to 40V (1N5822)

EXAMPLE						
PREFERRED P/N PART NO. PAG		PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION		
1N5820 A0	1N5820	A0				
1N5820 A0G	1N5820	A0	G	Green compound		

RATINGS AND CHARACTERISTICS CURVES

(TA=25°C unless otherwise noted)



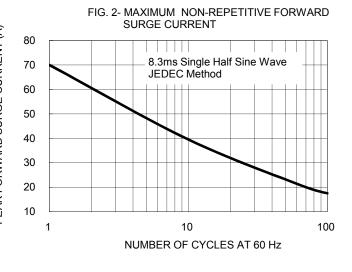
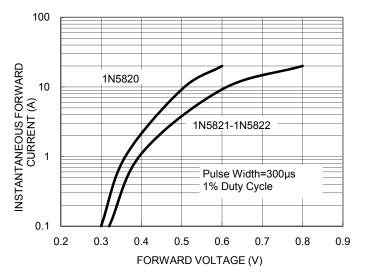
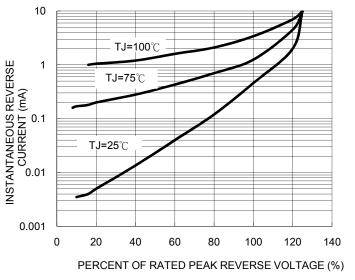


FIG. 3- TYPICAL FORWARD CHARACTERISTICS









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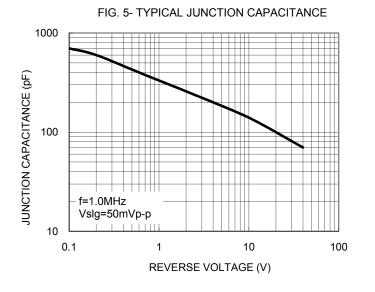
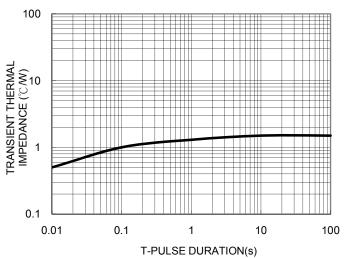
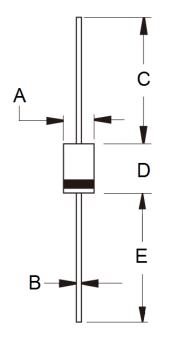


FIG. 6 TYPICAL TRANSIENT THERMAL IMPEDANCE



DIMENSIONS



P/N

YWW

G

F

	DIM.	Unit	(mm)	Unit (inch)		
		Min	Мах	Min	Max	
I	А	5.00	5.60	0.197	0.220	
I	В	1.20	1.30	0.048	0.052	
	С	25.40	-	1.000	-	
	D	8.50	9.50	0.335	0.375	
I	Е	25.40	-	1.000	-	

MARKING DIAGRAM



- = Specific Device Code
- = Green Compound
- = Date Code
 - = Factory Code



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